

MGA-22003

2.3-2.7 GHz 3x3mm WiMAX/WiBro and WiFi Linear Amplifier Module



Data Sheet

Description

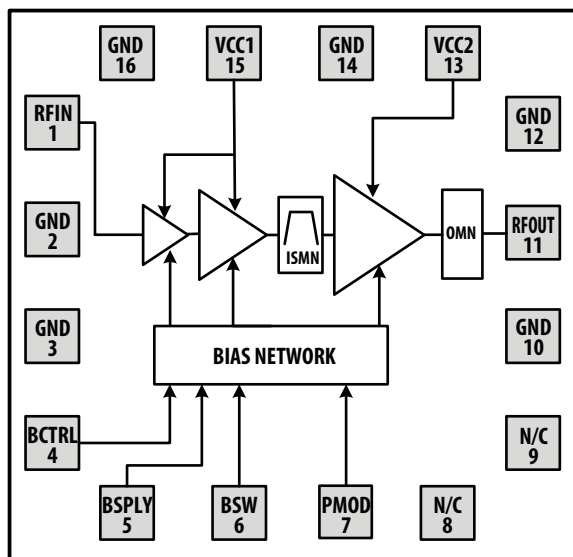
Avago Technologies MGA-22003 linear power amplifier is designed for mobile and fixed wireless data applications in the 2.3 to 2.7 GHz frequency range. The PA is optimized for IEEE 802.16 WiMAX/WiBro modulation but can be used for any high linearity applications. The PA exhibits flat gain and good match while providing linear power efficiency to meet stringent mask conditions. It utilizes Avago Technologies proprietary GaAs Enhancement-mode pHEMT technology for superior performance across voltage and temperature levels.

The MGA-22003 is packaged in a 3x3x1 mm package for space-constrained applications.

Applications

- Portable WiMAX/WiBro and WiFi applications
- WiMAX/WiBro and WiFi Access points

Functional Block Diagram



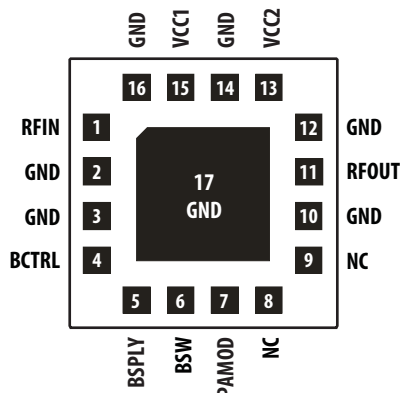
Features

- Advanced GaAs E-pHEMT
- 50 Ω all RF ports
- 10dB gain step in low power mode with I_{dsq} reduction
- Integrated CMOS compatible pins for shutdown and low power mode
- 3 to 5V supply
- Adjustable bias current with BCTRL pin
- ESD protection all ports above 1000V HBM
- Small size: 3 x 3 x 1 mm
- Stable under all loads or conditions
- -40°C to +85°C operation

At 2.5GHz (BCTRL = 2.8V)

- Gain of 35dB
- PAE of 19% at SEM compliant P_{out} = 25dBm
- Meets 802.16 masks at 25 dBm P_{out}, 16QAM WiMAX with 3.3V and 512mA
- 16QAM WiMAX EVM < -32dB (2.5%) at 25dBm
- Low power I_{dd}, 80mA at P_{out} = 0dBm, 10dB Gain Step

Package Diagram



Electrical Specifications

Absolute Minimum and Maximum Ratings

Table 1. Minimum and Maximum Ratings

Parameter		Specifications				Comments
Description	Pin	Min.	Typical	Max.	Unit	
Supply Voltage	VCC1 VCC2		3.3	5.5	V	
Bias Supply	BSPLY	3	3.3	5.5	V	
Bias Control	BCTRL	1.65	2.8	5.5	V	
Bias ON/OFF	BSW	1.65	1.8	5.5	V	
Mode Control	PAMODE	1.65	1.8	5.5	V	
RF Input Power	RFIN			15	dBm	Using 16QAM
MSL				MSL3		
Channel Temperature				150	°C	
Storage Temperature		-65		150	°C	

Table 2. Operating Range

Parameter		Specifications				Comments
Description	Pin	Min.	Typical	Max.	Unit	
Supply Voltage	VCC1 VCC2	3	3.3	5	V	
Bias Supply	BSPLY	3	3.3	5	V	
			13		mA	
Bias Control	BCTRL	2.75	2.8	2.85	V	
			.7		uA	
Bias ON/OFF	BSW	1.65	1.8	2.2	V	
			7	25	uA	
Mode Control	PAMODE	1.65	1.8	2.2	V	
			17	25	uA	
RF Output Power	RFOUT		25	27	dBm	Using 16QAM
Frequency Range		2.3		2.7	GHz	
Thermal Resistance, θ_{ch-b}			23.4		°C/W	Channel to board
Case Temperature		-40		+85	°C	

WiMAX (802.16e) Electrical Specifications

All data measured on an FR4 demo board at $V_{cc1} = V_{cc2} = 3.3V$, $BCTRL = 2.8V$, $T_c = 25^{\circ}C$, 50Ω at all ports. Unless otherwise specified, all data is taken with OFDM 16-QAM modulated signal per IEEE 802.16e with 10MHz BW operating over the BW of 2.3GHz to 2.7GHz.

Table 3. RF Electrical Characteristics

Parameter	Performance			Unit	Comments	
	Min.	Typical	Max.			
Input Return Loss		-10		dB		
Gain Flatness		1		dB	Over any 10MHz	
Gain Variation (V_{CC})	-1		1	dB	3V to 5V	
High Power Mode	EVM	-32	-27	dB	$V_{cc}=3.3V$	
		-34	-30		$V_{cc}=3.6V$	
	SEM-A @5.05MHz	-30.6	-13	dBm/100kHz	IBW=100kHz	
	SEM-B @6.5MHz	-22.3	-13	dBm/MHz	IBW=1MHz	
	SEM-C @10.5MHz	-26.6	-19			
	SEM-D @11.5MHz	-27.5	-25			
	SEM-E @15.5MHz	-35.3	-29.5			
	SEM-F @20.5MHz	-42.5	-37			
	Pout (SEM Compliant)	+25			dBm	802.16e
	Total DC Current		501	560	mA	Pout=25dBm
		464			Pout=24dBm	
Gain	32	35	38	dB		
Low Power Mode	EVM		-30	-	dB	Pout=0dBm
	Gain Step	8	10	15	dB	
	Total DC Current		70		mA	Pout=0dBm
P1dB		31		dBm	CW Single Tone	
Psat		32		dBm	CW Single Tone	
2fo		-12	-10	dBm/MHz	2.3-2.4GHz	
		-29	-27		2.5-2.7GHz	
3fo		-35	-27	dBm/MHz		
Settling Time	0.2	0.5		uS		
Icc leakage current		10	40	uA		
Noise Power in Cell Band		-142		dBm/Hz		
Noise Power in GPS Band		-133		dBm/Hz		
Noise Power in PCS		-137		dBm/Hz		

Selected performance plots

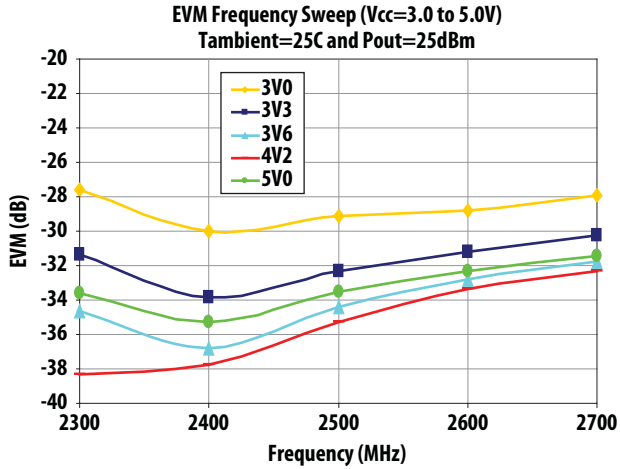


Figure 1. EVM Frequency Sweep at 25C and Pout=25dBm over Vcc

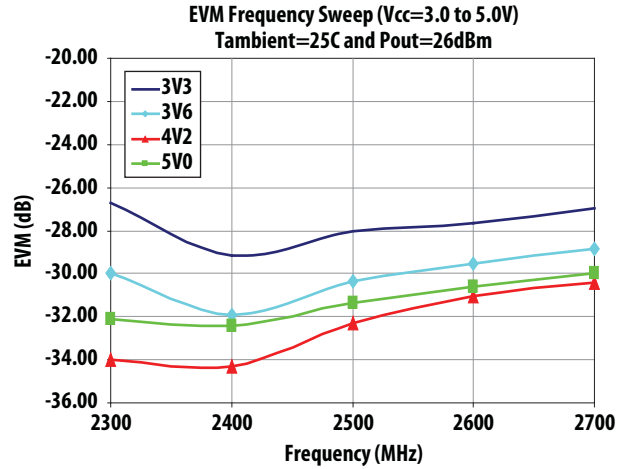


Figure 2. EVM Frequency Sweep at 25C and Pout=26dBm over Vcc

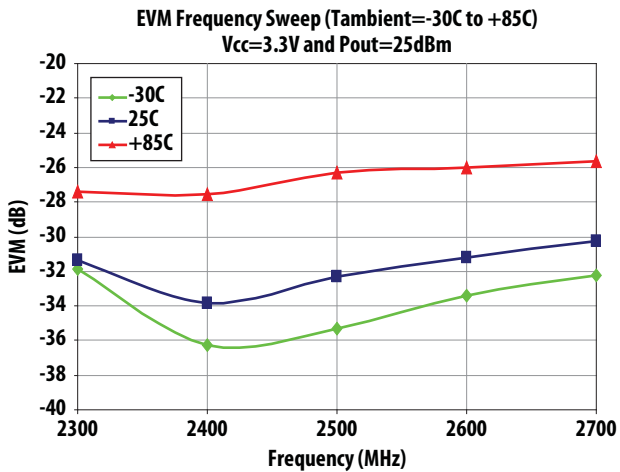


Figure 3. EVM Frequency Sweep at Vcc=3.3V and Pout=25dBm over Tambient

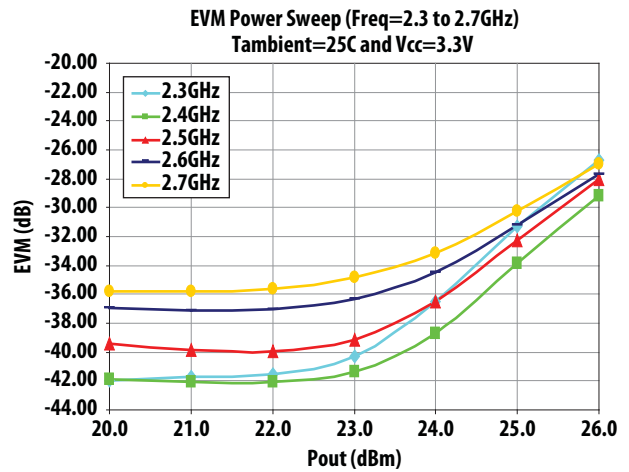


Figure 4. EVM Power Sweep at Vcc=3.3V and 25C over Frequency

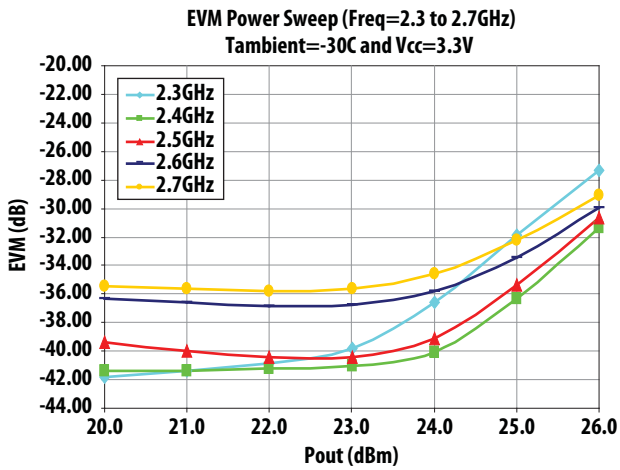


Figure 5. EVM Power Sweep at Vcc=3.3V and -30C over Frequency

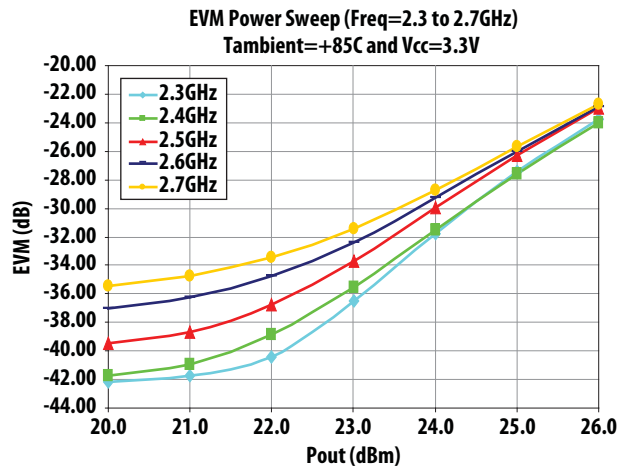


Figure 6. EVM Power Sweep at Vcc=3.3V and +85C over Frequency

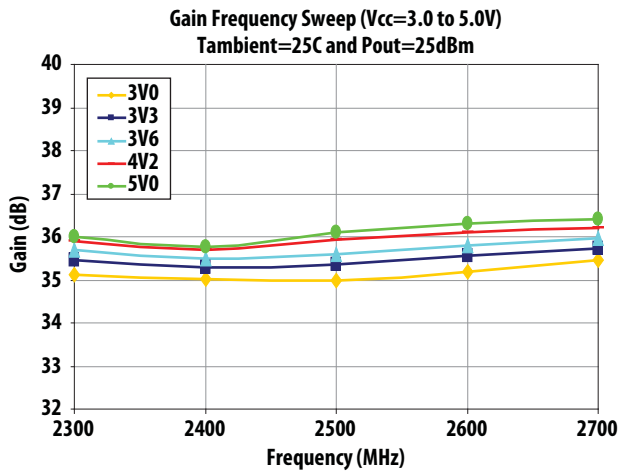


Figure 7. Gain Frequency Sweep at 25C and Pout=25dBm over Vcc

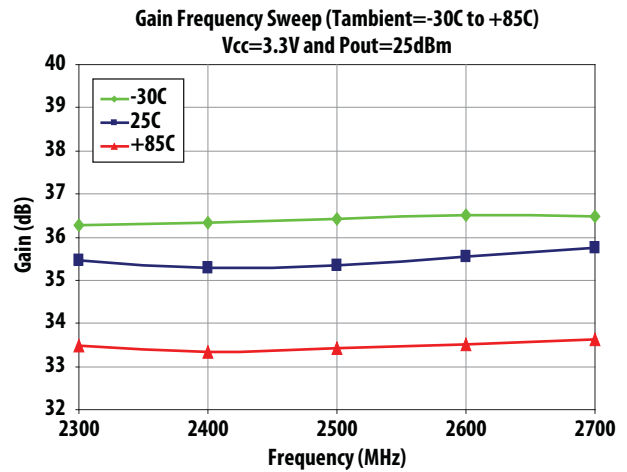


Figure 8. Gain Frequency Sweep at Vcc=3.3V and Pout=25dBm over Tambient

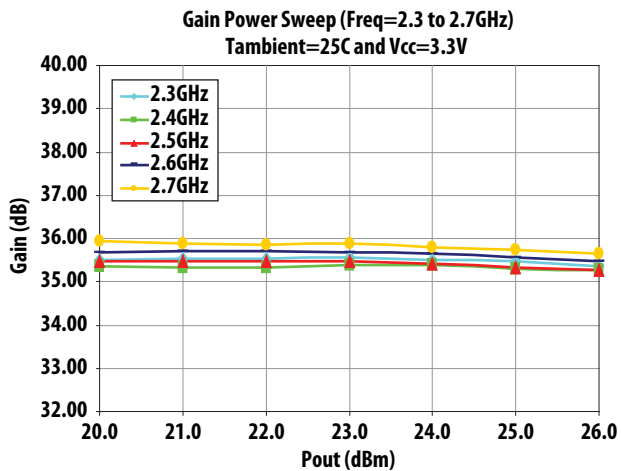


Figure 9. Gain Power Sweep at Vcc=3.3V and 25C over Pout

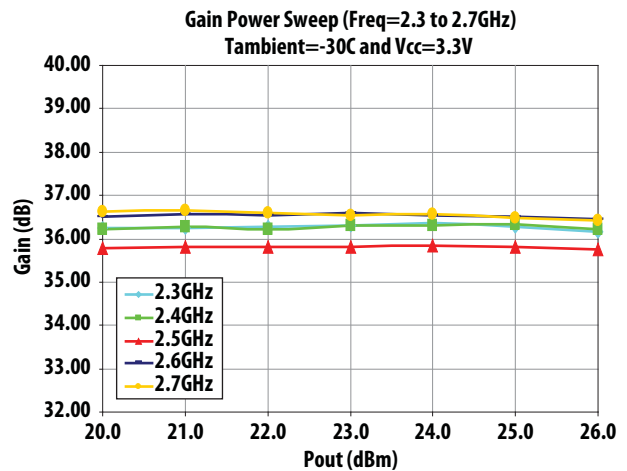


Figure 10. Gain Power Sweep at Vcc=3.3V and -30C over Pout

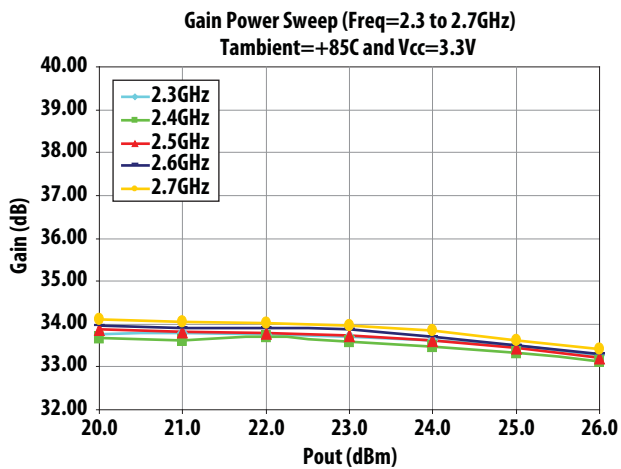


Figure 11. Gain Power Sweep at Vcc=3.3V and +85C over Pout

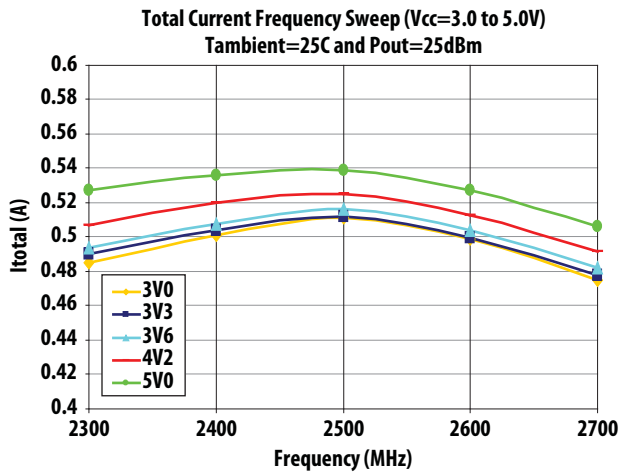


Figure 12. Total Current Frequency Sweep at 25C and Pout=25dBm over Vcc

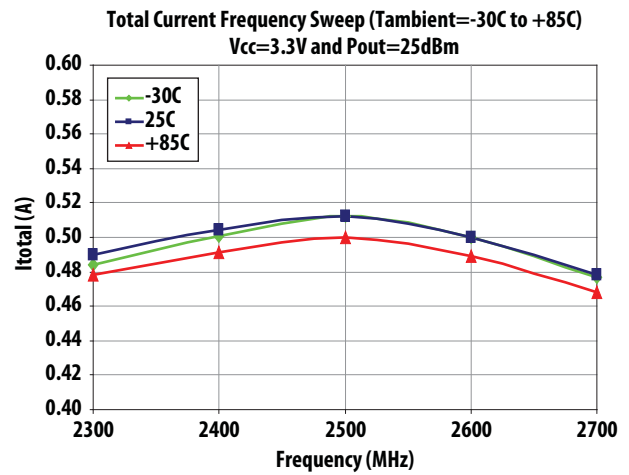


Figure 13. Total Current Frequency Sweep at 3.3V and Pout=25dBm over Tambient

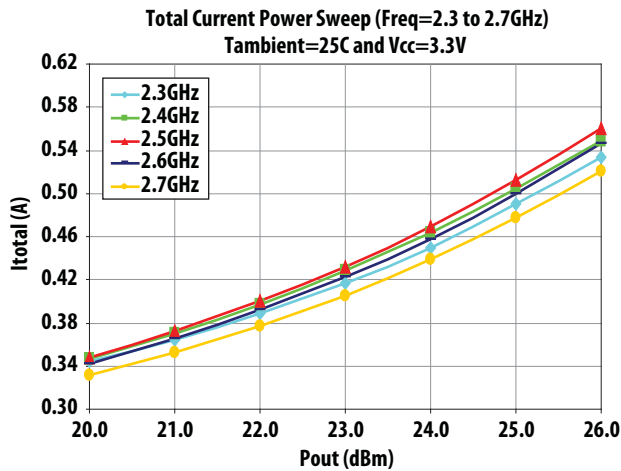


Figure 14. Total Current Power Sweep at 3.3V and 25C over Frequency

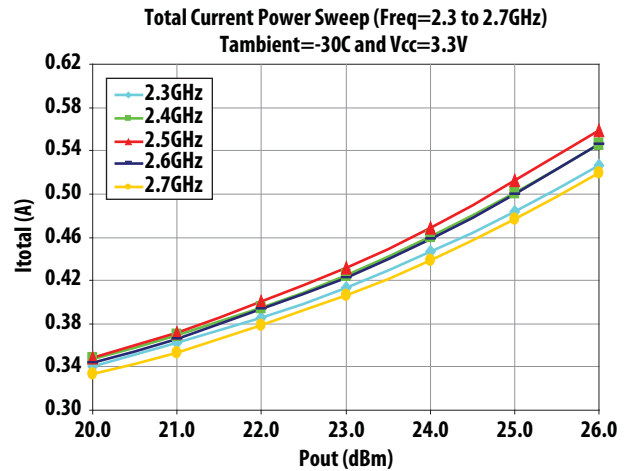


Figure 15. Total Current Power Sweep at 3.3V and -30C over Frequency

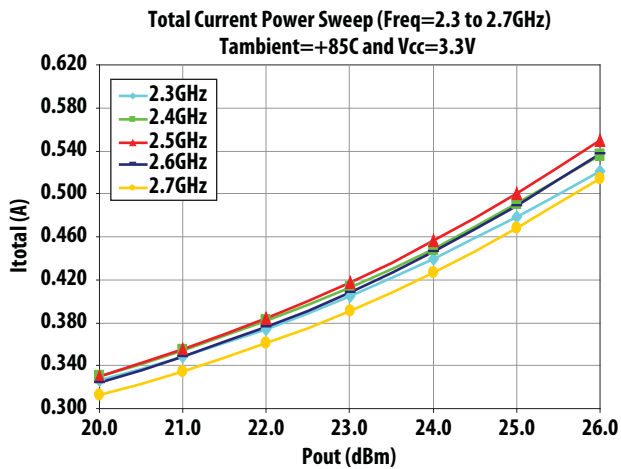


Figure 16. Total Current Power Sweep at 3.3V and +85C over Frequency

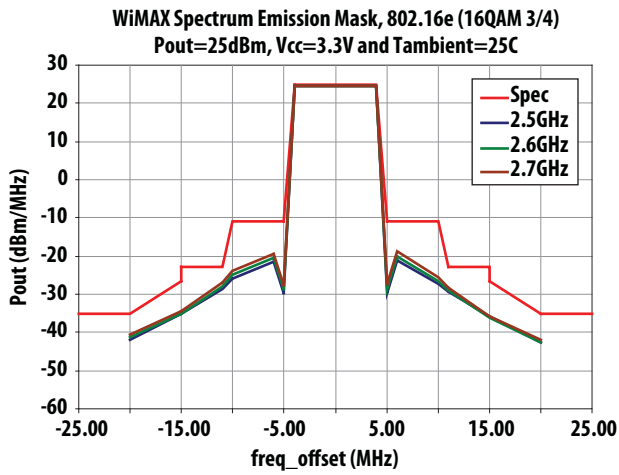


Figure 17. SEM Frequency Sweep at Vcc=3.3V and 25C (2dB Post-PA loss assumed)

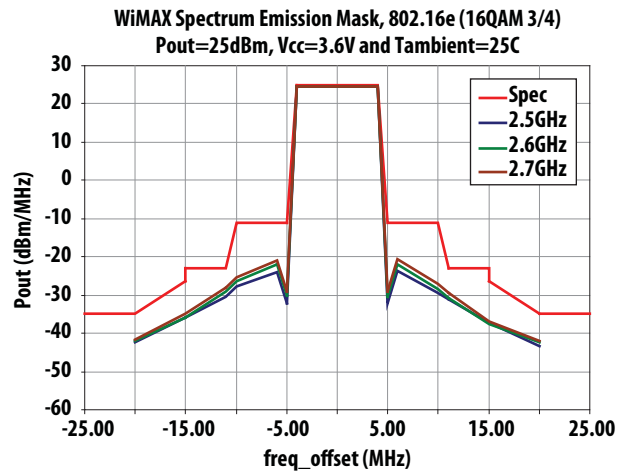


Figure 18. SEM Frequency Sweep at Vcc=3.6V and 25C (2dB Post-PA loss assumed)

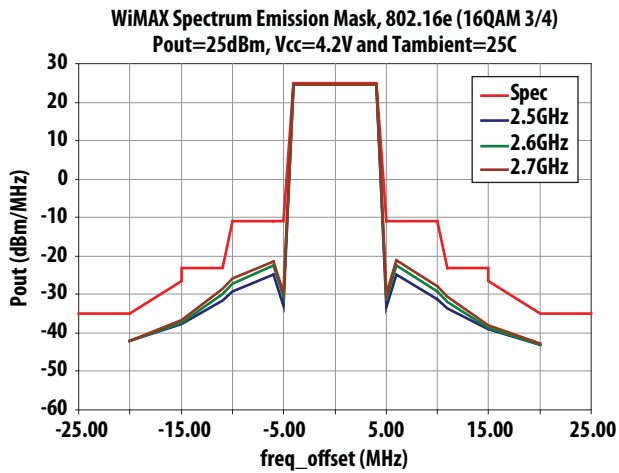


Figure 19. SEM Frequency Sweep at Vcc=4.2V and 25C (2dB Post-PA loss assumed)

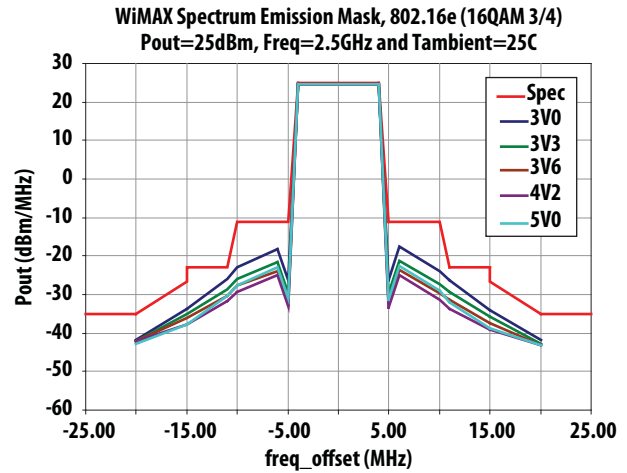


Figure 20. SEM at Vcc=3.3V, 25C and 2.5GHz over Vcc (2dB Post-PA loss assumed)

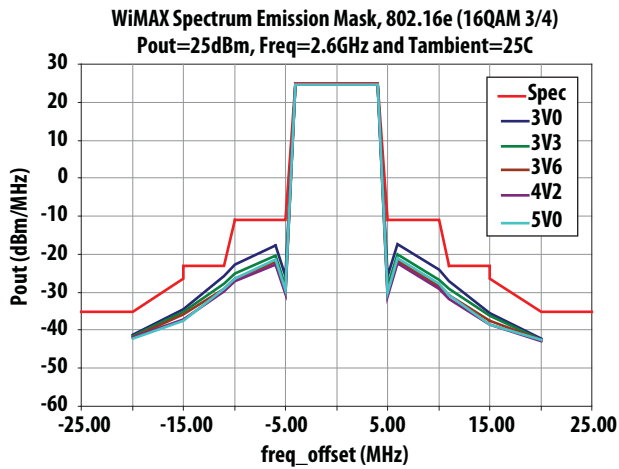


Figure 21. SEM at Vcc=3.3V, 25C and 2.6GHz over Vcc (2dB Post-PA loss assumed)

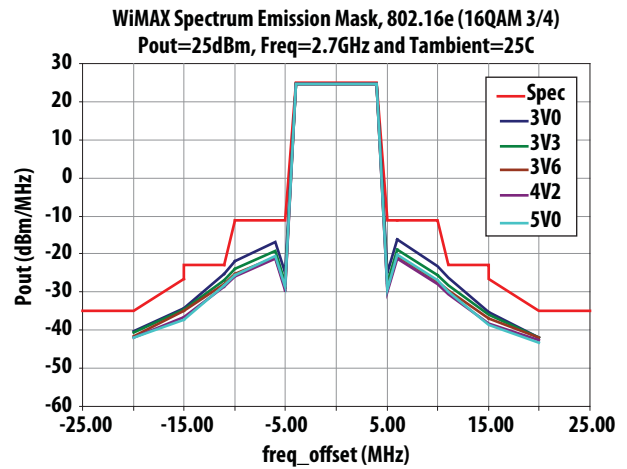


Figure 22. SEM at Vcc=3.3V, 25C and 2.7GHz over Vcc (2dB Post-PA loss assumed)

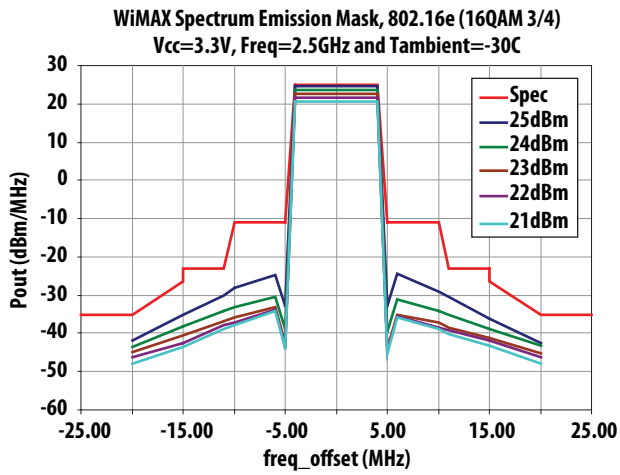


Figure 23. SEM at Vcc=3.3V, -30C and 2.5GHz over Vcc (2dB Post-PA loss assumed)

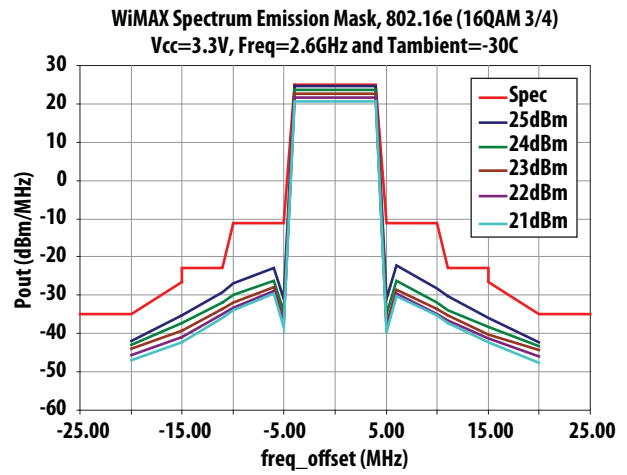


Figure 24. SEM at Vcc=3.3V, -30C and 2.6GHz over Vcc (2dB Post-PA loss assumed)

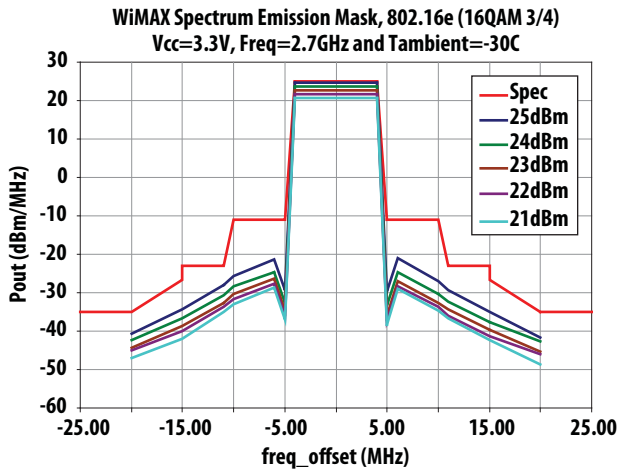


Figure 25. SEM at Vcc=3.3V, -30C and 2.7GHz over Vcc (2dB Post-PA loss assumed)

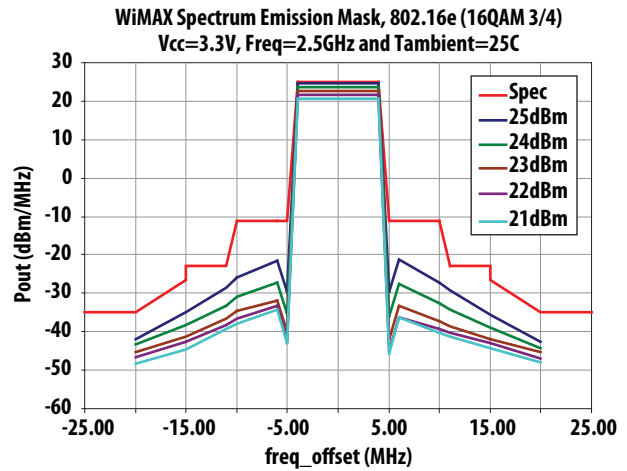


Figure 26. SEM at Vcc=3.3V, 25C and 2.5GHz over Vcc (2dB Post-PA loss assumed)

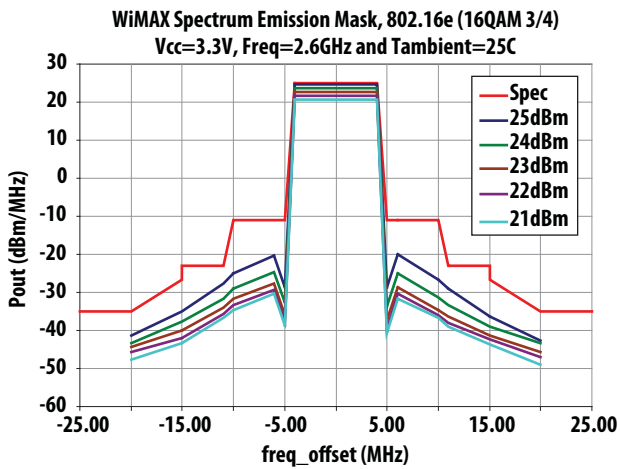


Figure 27. SEM at Vcc=3.3V, 25C and 2.6GHz over Vcc (2dB Post-PA loss assumed)

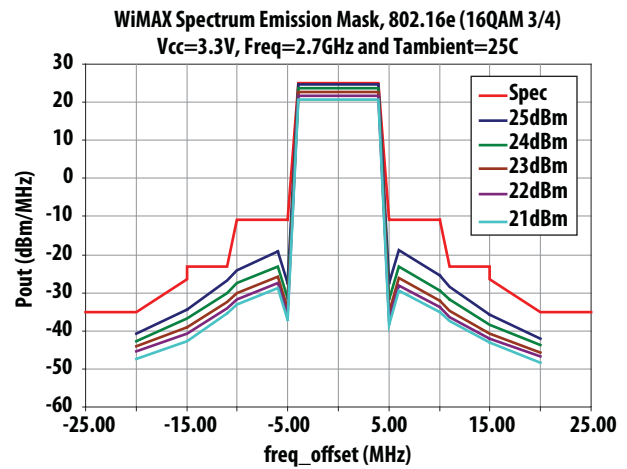


Figure 28. SEM at Vcc=3.3V, 25C and 2.7GHz over Vcc (2dB Post-PA loss assumed)

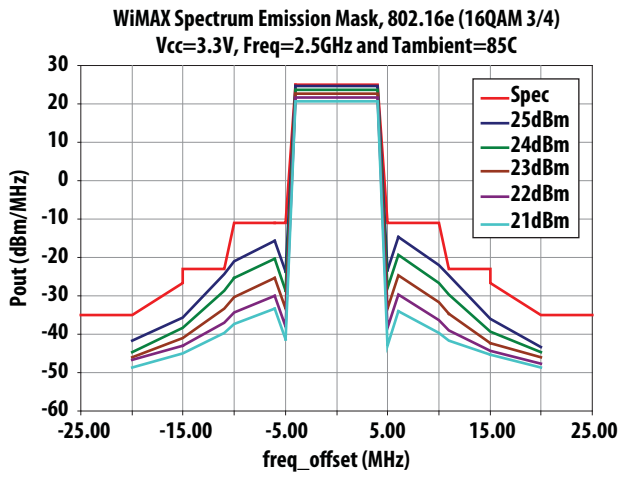


Figure 29. SEM at Vcc=3.3V, +85C and 2.5GHz over Vcc (2dB Post-PA loss assumed)

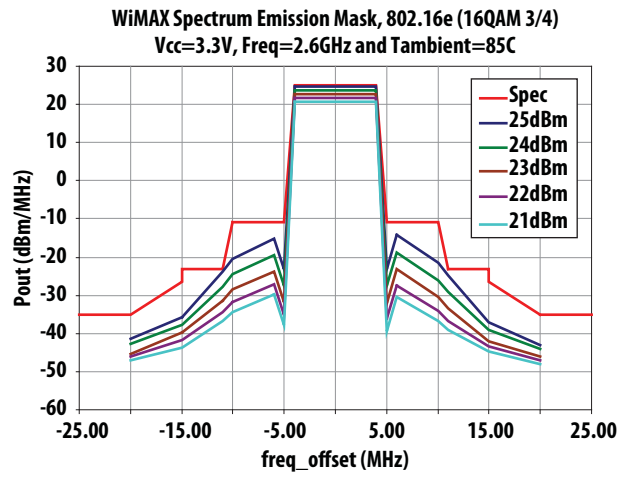


Figure 30. SEM at Vcc=3.3V, +85C and 2.6GHz over Vcc (2dB Post-PA loss assumed)

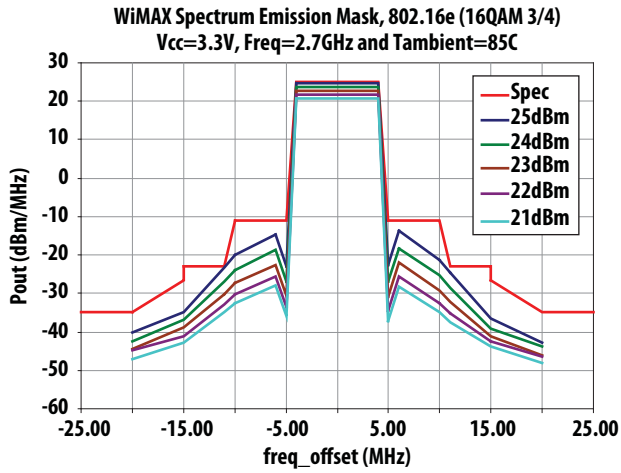


Figure 31. SEM at Vcc=3.3V, +85C and 2.7GHz over Vcc (2dB Post-PA loss assumed)

Evaluation Board Description

Table 4. Pin Description

Top Pin No.	Function	Bottom Pin No.	Function
1	VCC2	2	VCC2_S
3	B_SPLY	4	GND
5	VCC1	6	GND
7	NC	8	GND
9	PAMOD	10	GND
11	NC	12	GND
13	NC	14	B_SW
15	B_CTRL	16	GND
17	NC	18	GND
19	NC	20	GND

Recommended turn on sequence

- Apply VCC1 and VCC2
- Apply BSPLY
- Apply BCTRL
- Apply BSW
- For HPM Apply PAMOD HI
- For LPM Apply PAMOD LO
- Apply RF Input not to exceed 15dBm

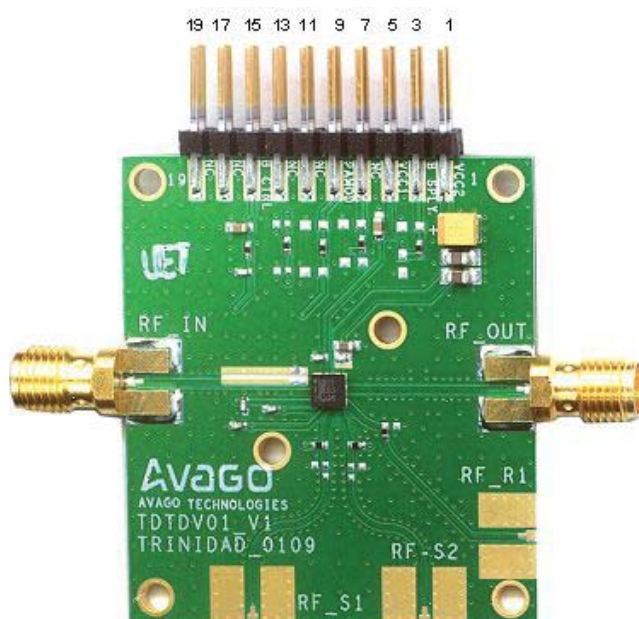
Turn off in reverse order

Typical Test Conditions:

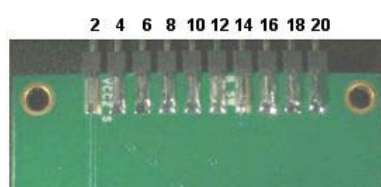
Pin	HPM	LPM	
VCC1,2	3.3V	3.3V	Supply Voltage
PAMOD	1.8V	0V	Low Power Mode
B_SPLY	3.3V	3.3V	Bias Voltage
B_CTRL	2.8V	2.8V	Bias Control
B_SW	1.8V	1.8V	PA Enable

Notes: VCC1, VCC2 and B_SPLY can be tied together to reduce supply voltages, but B_CTRL needs to be a regulated voltage which is optimized for 2.8V at Vcc of 3.3V. Other bias points are described under flexible BCTRL optimization section.

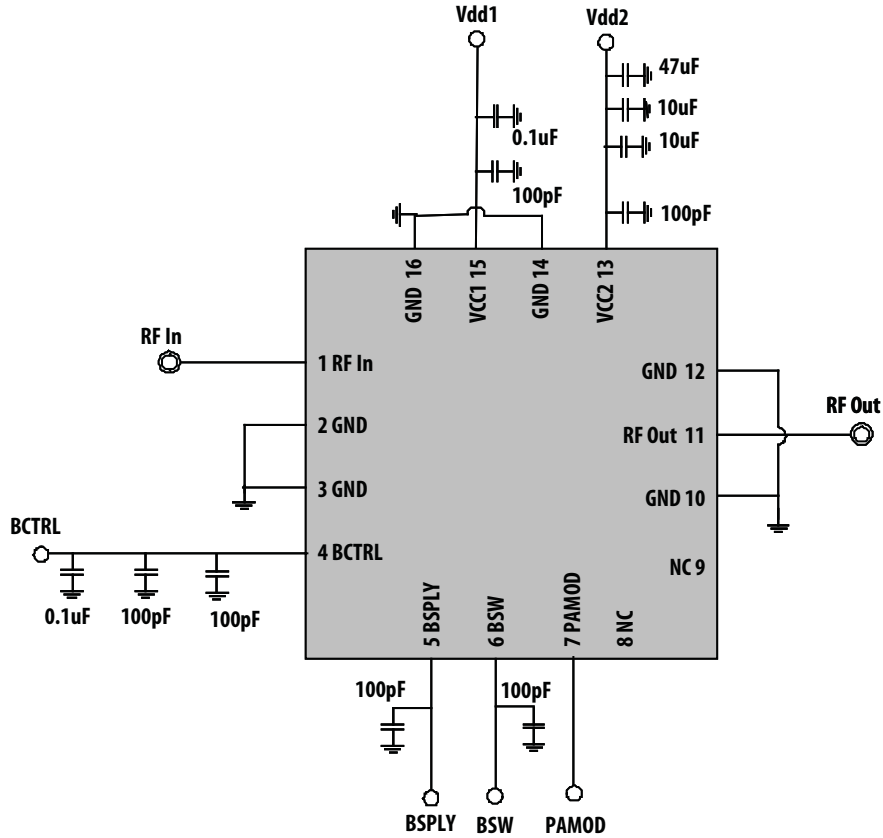
Demoboard Top Pins



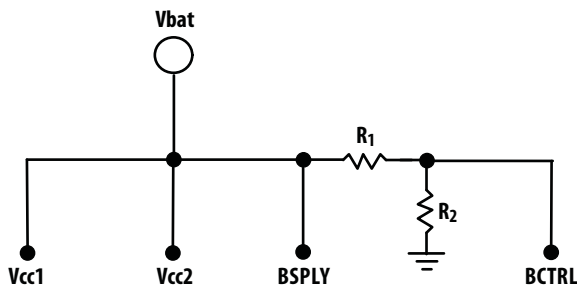
Demoboard Bottom Pins



Application Circuit MGA-22003



Using 3.3V or 5V Supply and tying Vcc1, Vcc2, BSPLY and BCTRL



Notes: BCTRL regulates the device current, thus R1 and R2 should have good tolerance rating. If available, a voltage regulator is the preferred method of bias.

In this example we set R2 at 40KOhm and solve for R1 with simple voltage divider equation. Note this method will cause some leakage current through R2.

3.3V Example :

$$V_{BCTRL} = \frac{R_2}{R_1 + R_2} * V_{BATT}$$

$$2.8V = \frac{40K\Omega}{R_1 + 40K\Omega} * 3.3V$$

$$R_1 = 7K\Omega$$

$$R_2 = 40K\Omega$$

Given :

$$V_{BCTRL} = 2.8V$$

$$V_{BAT} = 3.3V$$

$$R_2 = 40K\Omega$$

$$R_1 = ?$$

5.0V Example :

$$V_{BCTRL} = \frac{R_2}{R_1 + R_2} * V_{BATT}$$

$$2.8V = \frac{20K\Omega}{R_1 + 20K\Omega} * 5.0V$$

$$R_1 = 15.7K\Omega$$

$$R_2 = 20K\Omega$$

Given :

$$V_{BCTRL} = 2.0V$$

$$V_{BAT} = 5.0V$$

$$R_2 = 20K\Omega$$

$$R_1 = ?$$

Flexible BCTRL Optimization

BCTRL voltage on MGA-22003 directly controls the bias current of the device. If the user requires lower current or perhaps higher power than the typical operation, then this can be accomplished by a simple BCTRL change. A more sophisticated use might include BCTRL as part of a closed loop system where software dynamically adjusts BCTRL depending on the output power required.

Low Current Operation: 400mA at 25dBm Pout with BCTRL = 1.8V and VCC = 3.3V

Example 1 is very typical of mobile device application where ~400mA of current consumption is required. With the above settings at full power of 25dBm, IDD drops from 500mA to 418mA with some trade-off in EVM but still meeting SEM.

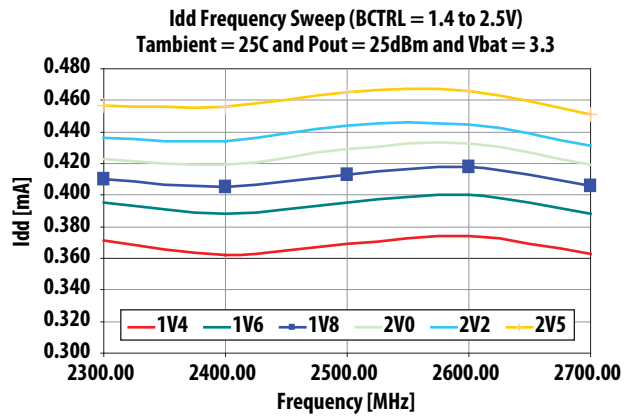


Table 5. Low Current Biasing
Optimal settings for BCTRL (2.3G - 2.7G)

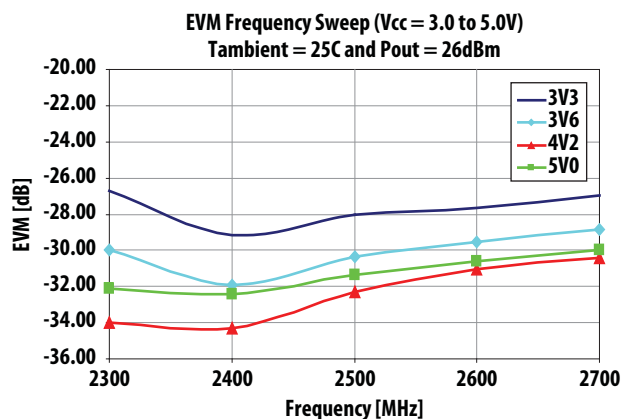
VCC = BSPLY = 3.3V			
Pout	BCTRL	Idd	EVM
25dBm	1.8V	418mA	-27.9dB
24dBm	1.7V	367mA	-27.6dB
23dBm	1.7V	330mA	-27.0dB
I _{dsq}	x	94mA	x

Table 6. Typical Biasing
Typical settings for BCTRL (2.3G - 2.7G)

VCC = BSPLY = 3.3V			
Pout	BCTRL	Idd	EVM
25dBm	2.8V	501mA	-32dB
24dBm	2.8V	464mA	-33dB
23dBm	2.8V	435mA	-35dB
I _{dsq}	x	240mA	x

Hi Power Operation: 26dBm Pout with BCTRL = 2V and VCC = 5V

Example 2 is more typical of CPE applications where current consumption is less important and higher power is required. With BCTRL at 2V and VCC at 5V MGA-22003 is able to achieve higher than 26dBm Pout and still meet SEM. Generally as VCC increases SEM improves.



Land Pattern

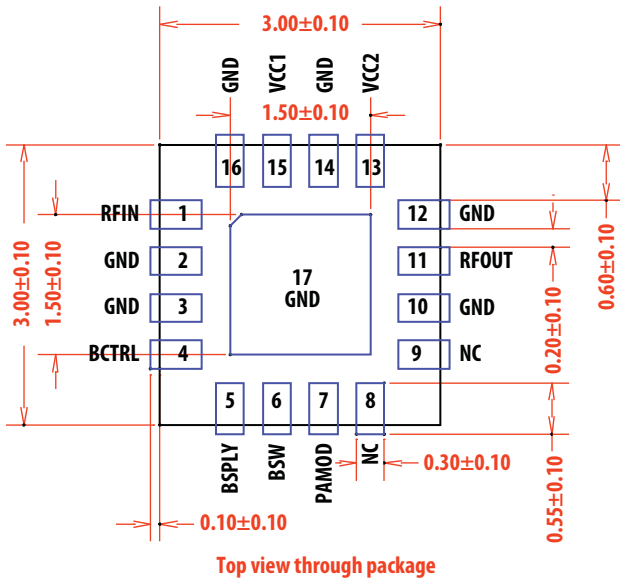


Figure 32. Recommended footprint

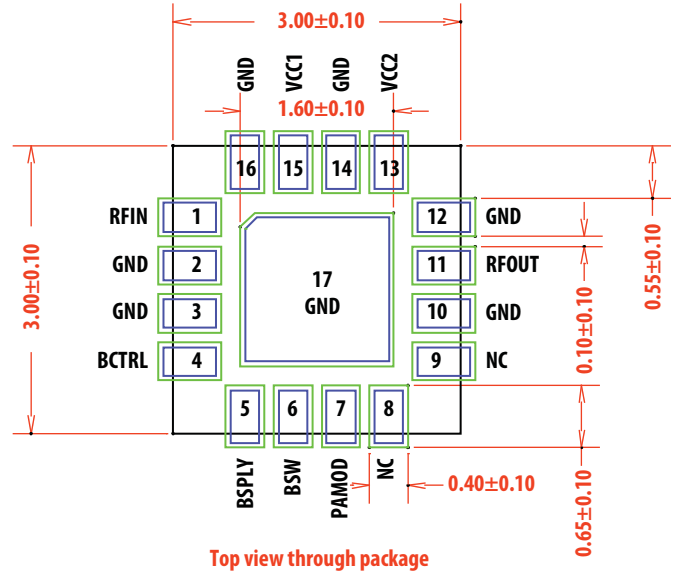


Figure 33. Recommended soldermask opening

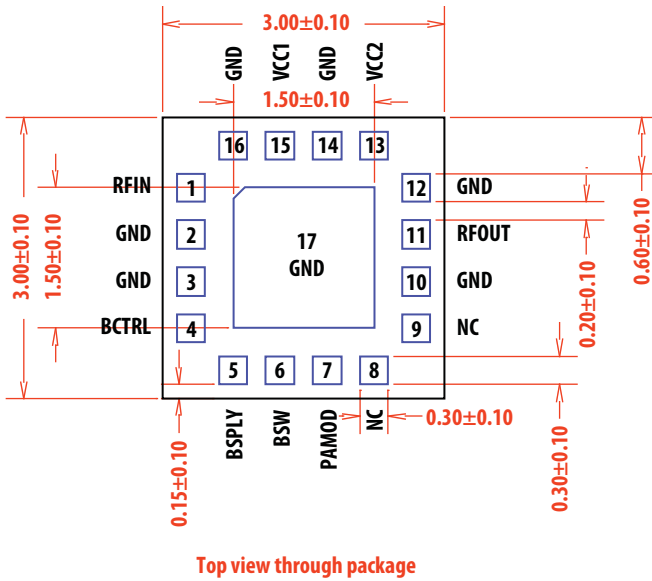


Figure 34. Package dimensions

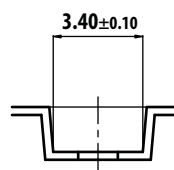
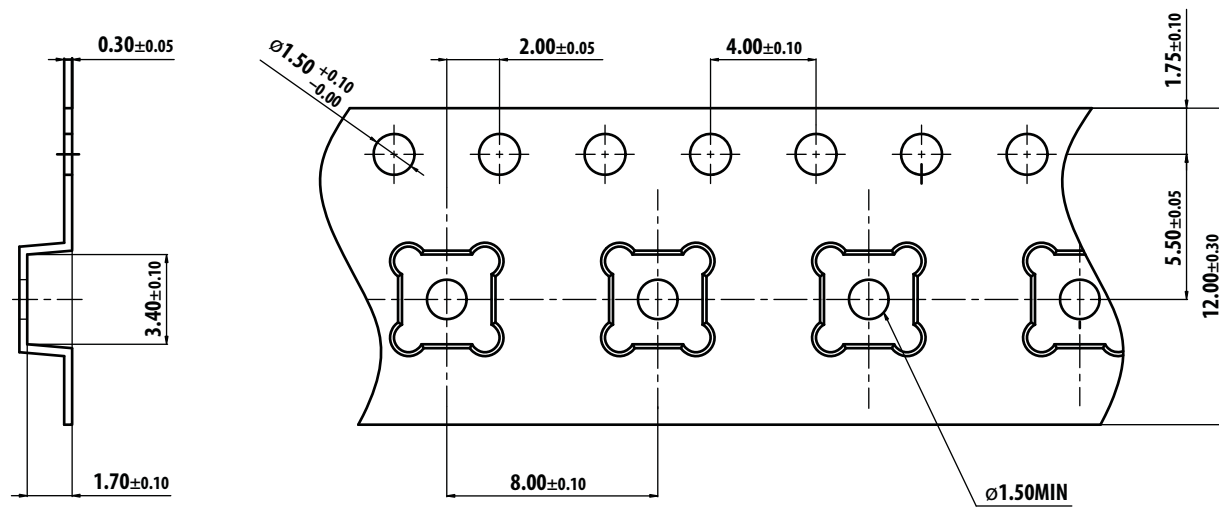
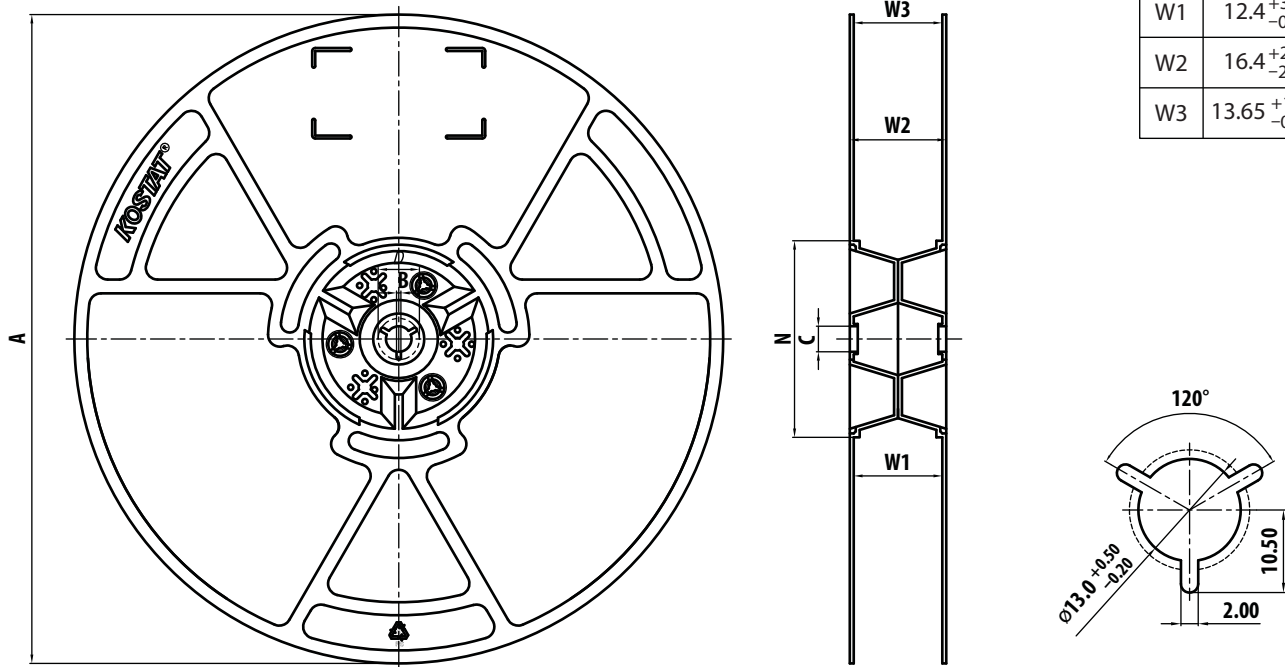
- Notes:
1. All units are in millimeters
 2. package is symmetrical

Ordering Information

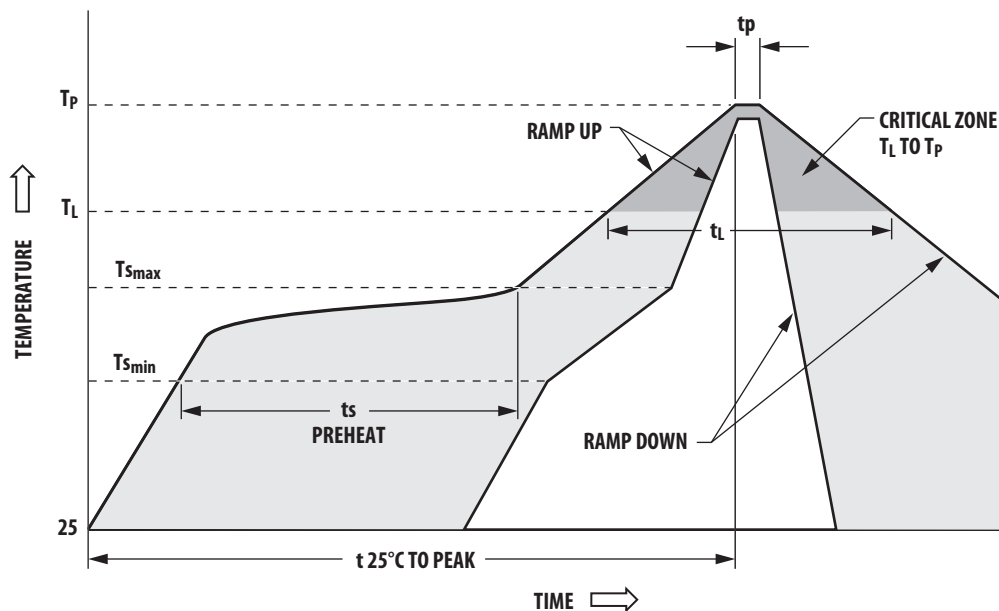
Part Number	No. of Devices	Container
MGA-22003-BLKG	100	7" Reel
MGA-22003-TR1G	3000	13" Reel

Size	12mm
A	330 ^{+2.0} _{-2.0}
B	1.5min.
C	13.0 ^{+0.5} _{-0.2}
D	20.2min.
N	100 ^{+3.0} _{-0.0}
W1	12.4 ^{+3.0} _{-0.0}
W2	16.4 ^{+2.0} _{-2.0}
W3	13.65 ^{+1.75} _{-0.75}

Tape and Reel Information



Handling and Storage



Profile Feature	Sn-Pb Solder	Pb-Free Solder
Average ramp-up rate (TL to TP)	3°C/sec max	3°C/sec max
Preheat		
- Temperature Min (T _{smin})	100°C	100°C
- Temperature Max (T _{smax})	150°C	150°C
- Time (min to max) (t _s)	60-120 sec	60-180 sec
T _{smax} to T _L		
- Ramp-up Rate		3°C/sec max
Time maintained above:		
- Temperature (T _L)	183°C	217°C
- Time (T _L)	60-150 sec	60-150 sec
Peak temperature (T _p)	240 +0/-5°C	260 +0/-5°C
Time within 5°C of actual Peak Temperature (t _p)	10-30 sec	10-30 sec
Ramp-down Rate	6°C/sec max	6°C/sec max
Time 25°C to Peak Temperature	6 min max	8 min max

Typical SMT Reflow Profile for Maximum Temperature = 260+0/-5°C

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